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Atty. Docket No. 8013-1055

PATENTS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Atsushi YAMAGUCHI et al.

Confirmation No. 6543

Serial No. 09/816,754

GROUP 2826

Filed March 26, 2001

Examiner Remmon R. Fordé

NITRIDE BASED SEMICONDUCTOR
PHOTO-LUMINESCENT DEVICE

SUPPLEMENTAL AMENDMENT AFTER FINAL REJECTION

Commissioner for Patents
PO Box 1450
Alexandria, Virginia 22313-1450

Sir:

In further response to the Official Action of January 28, 2003, and responsive to the requirement to file a statement of the substance of the interview conducted on May 6, 2003, as set forth in the Examiner Interview Summary Record mailed May 7, 2003, please amend the above-identified application as follows:

Kindly make of record the attached literature material:

GÖTZ et al., "Activation energies of Si donors in GaN,"
Appl. Phys. Lett. **68** (22), pp. 3144-3146 (1996); and

*Introduction to Nitride Semiconductor Blue Lasers and
Light Emitting Diodes*, p. 135, Ed. NAKAMURA et al., Publ. Taylor
& Francis (2000).

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